Optical patterning of magnetic domains and defects in ferromagnetic liquid crystal colloids

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A promising approach in designing composite materials is han n_{xy} all ph_{xy} ical beha ior combines x_y olid nance r c rest and orien a ionall ordered x_y of material here may α_y cale. S ch composites can no onl inherit properies of heir consistency i ends beha ior x_y chas ferromagnetic ordering of colloidal metal nanoparticles forming may α_y copic magnetia i a ion domains, hen dis perse ed in a nematic liq id cr x_y al. Here, e demons, rate here op ical paterning of domains, r c rest and opological defects in the ferromagnetic liq id cr x_y al colloids, hich allo x_y for all ering heir rest ponset of magnetic elds. O r indings re eal here na re of he defects in his x_y of materials x_y em hich is differential compared o non-polar nematics and ferromagnes alike. © 2015 AIP P b s LLC. [h p://d.doi.org/10.1063/1.4928552]

Liq id cr_{xy} al (LC) colloid, a rac a considerable amo n of c_x cien i c in eras, dri en b he richness of heir

ill mina ion, 95 μ l of pen lc anobiphen 1 (5CB, Cheng hi Yongh a Di pla Ma erial Co. L d.) a mi ed i h 5 μ l of a oben ene-con aining Beam 1205 LC (Beam Co.). Nonis omeri ing FLCC₂ (pro ocol 2) ili ed for_s rface-enabled op ical defec pa erning ere based on s_{s} ing 100 μ l of p re 5CB a, he ho, medi m, b he prepara ion pro ocol a, he s ame o her is e. Silane-PEG capped magne ic nanopla eles di per ed in e hanol ere hen added o he LC hile follo ing he dispersion proced respectively reported pre io $s_{s} = 1.5 \, \mu$ of e hanol a added o 15μ l of he LC mi re o bring i o he is o ropic phase, follo ed b adding $15 \,\mu$ l of 0.5 1 .% magne ic pla eles di per ed in e hanol. Thes ample a kep a 90°C for 3h of ll e apora e he e hanol, ielding an e cellen di per ion in he i o ropic pha e a ero eld, and hen a rapidl cooled o he nema ic pha e of he mi re hile igoro, 1, irring. The en ing FLCC a cen rif ged a 2000 rpm for 5 min o remo e re id al aggrega ion o ha he nal composite con ained onl ell-di per ed pla eles. The nal frac ion of magne ic pla eles in he LC a aried i hin 0.05 0.1 .%, as de ermined based on absorbance and magne i a ion al e_s. Nanopla ele_s e hibi ed_s pon aneo., alignmen i h large-area face, or hogonal o $\mathbf{n}(\mathbf{r})$ and magne ic momens along $\mathbf{n}(\mathbf{r})$, as con rmed b meas ring polari a ion-dependen ab, orbance¹⁶ and probing re, pon, e of heir dil e di per ion o magne ic eld. Di per ion of ferromagne ic pla eles in he LC mi re eres able a all s ed eld, (p o 20 mT) e hibi ing a facile re pon e alread a eld belo 1 mT. Homeo ropic glas cell i h pol domain FLCC and M pointing in one of the o an i-parallel direcion, along he erical far-eld direc or \mathbf{n}_0 ere prepared sing 1- or 0.17-mm hick glass place readed in an aq eossol ion of 0.1 .% N,N-dime h 1-N-oc adec 1-3-aminoprop 1- rime ho sil 1 chloride (DMOAP, Acros Organics) ia dip-coa ing. The cell gap hickness of $30 \,\mu m$ or $60 \,\mu m$ $a_{j,s} \in b$ in er_{s} pacing he glass place a heir edge i h UV-c rable op ical adhe, i e (NOA-65, Norland Prod c_{s}) or epo con aining, ilica, pacer, of corre ponding diame er, Cell lling a done a room empera re sing capillar ac ion. FLCC cells e hibi s pon aneos forma ion of random magne ic domain, of la eral dimen ion, picall comparable or some ha larger han he cell hickness and dependen on he ini iali a ion eld of 10 35 mT (Ref. 4 and 16) (Fig. 1

he orien a ion of $\mathbf{M}(\mathbf{r})$ ip, o an oppo i e in-plane orien aion, a, depic ed in Fig. 3(b), al ho gh $\mathbf{n}(\mathbf{r})_{c_{5}}$ a_{-c_{5}} con in o_{-c_{5}} (Fig. 3(a)) beca_{-c_{5} e half-in eger defec_{c_{5}</sub> are allo ed in he $\mathbf{n}(\mathbf{r})$ line eld b no in he $\mathbf{M}(\mathbf{r})$ ec or eld.

Al ho gh, in principle, im l aneo, pa erning of bo h $M(\mathbf{r})$ and $\mathbf{n}(\mathbf{r})$ can be achie ed b combining he 0 approache de cribed abo e, i i in ere ing o no e he e ol ion of domain_s r c reg in $\mathbf{M}(\mathbf{r})$ hen onl he direc or is pa erned (Fig. 4). The $M(\mathbf{r})$ i hin magne ic domain, in he pa erned region follo s_{α} hesp a iall ar ing $\mathbf{n}(\mathbf{r})$ i hin he magne ic domain, and beha e di con in o.s l (ipping o oppo, i e domain,) a he in er-domain all. A applied magne ic eld, he pol domain na re of he FLCC in erplas i h he opologicall req ired all connec ing he halfin eger defec line, in $\mathbf{n}(\mathbf{r})$, ca., ing a comple pa ern of domain and all defecs in $e_{r_{2}}$ pacing hem, hich lo 1 e ol e i h ime and rongl depend on bo h he direc ion and s_{S} reng h of **B**. In ere, ingl, he id h of all defecs i hin he region of di or ed $\mathbf{n}(\mathbf{r})$ i of en larger han ha in region of niform direc or (Fig. 4). To not er he na re of magne ic in er-domain all in he FLCC, e s ed dark eld micros cop obser a ions; ha re eal bo h loca ions; and oriena ion, of indi id al nanopla eles \int_{S} pplemen ar ideo S1)²² a ero eld and hen **B** a differen orien a ion a elec i el s i che he domain of opposi e M. Unlike in con en ional magne ic s_{1} , s_{2} , s_{3} , here magne ic domain, are picall



FIG. 4. POM image, of FLCG, i h pho o-pa erned defec₅. (a) A micrograph of he₅ r c re corre, ponding o $\mathbf{n}(\mathbf{r})_5$ ho n in Fig. 3, i h he all in $\mathbf{M}(\mathbf{r})$ is ible a, a brigh jiggling line. An in-plane **B** along oppo, i e direction, marked in (b) and (c)₋₅ i che, complement ar domain, i h an i-parallel non-niform $\mathbf{M}(\mathbf{r})$. (d) (i) POM image, of he FLCC cell i h a di, clina ion pair. The in er-di, clina ion and o her **M**- all defec₅, separa ing magne ic domain, are clearl is ible. Polari ing micrograph, (a) (d) and (g) ere aken i h cross ed polari er $7\mathbf{P}'$ and anal er $7\mathbf{A}$, i hile he respective to bained i h parallel **P** and **A**, $\mathbf{a}_{s,5}$ ho n \mathbf{s}_{s} ing hie do be arrows. The red-ligh ill mina ion \mathbf{s}_{s} ed in (g) (i) pre en nin ended change, of \mathbf{s}_{s} reface bo ndar condition, hro gh pho oalignmen d ring imaging. The comparison of micrograph, (d f) and (g i), hich ere aken $\approx 10 \text{ min}$ after (d f), demon, ra $\mathbf{e}_{s,5}$ lo e ol ion of domain, i h ime.

 a_{s} epara ed b he_s o-called Bloch or Néel all ⁸ i h con in o_{s} albei locali ed_s oli onic deformation of $M(\mathbf{r})$, magne i a ion a he in er-domain all of he FLCC is no de ned, s_{0} o ha he are sing lar in na re. This is because M(r) and $\mathbf{n}(\mathbf{r})$ are s rongl co pled, s o ha he s oli onic deformations of $\mathbf{M}(\mathbf{r})$ be een he domain, o ld be co, l in erm, of he corresponding elas ic deformations of $n(\mathbf{r})$. In ead, he domain all in he FLCC ha e niform direc or b nde ned $M(\mathbf{r})_{r,s}$ o ha here is no $\mathbf{a}_{r,s}$ ocia ed elas ic free energ $\mathbf{c}_{s,s}$ d e o.s. ch all. A applied eld, he in er-domain all can be par iall depri ed of nanopar icles is pplemen ar ideo S1) and ranging in id h from he a erage pacing be een indi id al nanopar icle, o $\sim 1 \mu m$, a, de ermined b colloidal in erac ion be een nanopla ele_{S} i h differen l orien ed dipole momens of he neighboring domain, of oppo- \mathbf{x}_{s} i e $\mathbf{M} \| \mathbf{n}_{0}$. When $\mathbf{n}(\mathbf{r}) \| \mathbf{M}(\mathbf{r})$ i hin he domain is die or ed, hi in erpla i f r her al ered b he energe ic co of ela ic di or ion (Fig. 4). Al ho gh he domain all defec_s in he FLCC are s_{1} ing lar in M(r), differen from he s_{2} oli onic Bloch or Néel all commonl ob er ed in magne ic. s em_s,⁸ one-, o-, and hree-dimen, ional is ed_s oli on, can als o form in he chiral con erpars of he FLCC, in hich \mathbf{j} ed $\mathbf{n}(\mathbf{r}) \parallel \mathbf{M}(\mathbf{r})_{S}$ r c reg are promo ed b he chiral naid.¹⁶ re of he LC ho

Unlike con en ional LC, hich e hibi a re pon, e o magne ic eld, ha i, m ch læ, facile han he re pon, e o elec ric eld, he FLCC, are, i ched a $\approx 1 \text{ mT}$ eld, and e hibi polar re pon, e. Al ho gh ei her onl magne icall niform or random pol domain FLCC, ample, ere, died preio, 1,^{4,7,16} o r ork demon, ra e, ha he magne ic domain, can be pa erned on mæ o, copic leng h₅ cale, in man differen a., h., allo ing for engineering he macro, copic re, pon, e of, ch ma erial, o magne ic eld. Since hi, pa erning i, achie ed in a re-con g rable fa, hion, , ing lo -in en, i ie, of ligh, o r nding, ma enable dæ ign, and implemen a ion, of mæ, o, r c red, of ma er compo, i æ,

i h n_{x_5} al proper is, and facile pre-de ned re, pon, e, o eak e ernal₅ im li. Be ond he po en ial pracical x_5 e, he e perimen al frame ork e ha e de eloped ma allo one α_5 d ho he polar na re of ordering in₅ of ma er gi e, ri, e o ne pe, of opological defec₅ and₅ oli on, . In addiion α_5 mall-molec le liq id cr.₅ alline h α_{x_5} of magne ic nanopar icle, he FLCC ordering can po en iall be pa erned in pol meric, ela, omeric, and o her₅ of ma er₅ x_5 em₅.

To concl de, e ha e demon, ra ed he op ical pa erning of magne ic domain, and defec_s in he FLCC_s. Beca_s e of he facile magne ic_s i ching i h ea, il con g rable domain polari and ela, ic di, or ion pa erning, o r e perimen al frameork ma lead o reali ing_{-s} r c re, and compo i e, ell be ond he one, pre, en ed in hi, le er. The in rod c ion of chirali and par icle-like e ci a ion, can enable magne ic conrol of comple op ical phenomena_{+s} ch a, nema icon formaion and de ec ion, ¹⁷ s elec i e re ec ion ning, ^{18,19} noncon ac manip la ion of defec_s, ^{20,21} e c. Moreo er, pol mer or ela, omer ne ork_s in he FLCC_s ma ield no el mechanical beha ior of he en, ing_{-s} of _s olid_s, _s ch a, programmable _s rain bia, a and_s elec i e mechanical ac a ion. ^{12,14}

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16